**BAS28** 

#### **FEATURES**

- · Small plastic SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA.

#### **APPLICATIONS**

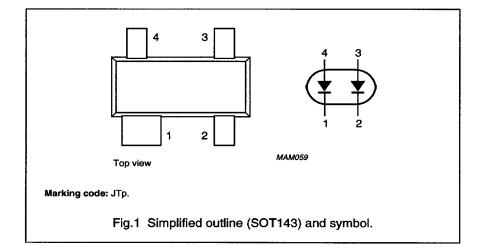
 High-speed switching in e.g. surface mounted circuits.

#### **DESCRIPTION**

The BAS28 consists of two high-speed switching diodes, fabricated in planar technology, and encapsulated in the small plastic SMD SOT143 package. The diodes are not connected.

#### **PINNING**

PIN	DESCRIPTION
1	cathode (k1)
2	cathode (k2)
3	anode (a2)
4	anode (a1)



## **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage		_	85	٧
V <sub>R</sub>	continuous reverse voltage			75	٧
l <sub>F</sub>	continuous forward current	see Fig.2; note 1	_	215	mA
IFRM	repetitive peak forward current		_	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		t = 1 μs	-	4	Α
		t = 1 ms	-	1	Α
		t = 1 s	_	0.5	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	<b>–</b>	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

#### Note

1. Device mounted on an FR4 printed-circuit board.

**BAS28** 

#### **ELECTRICAL CHARACTERISTICS**

T<sub>i</sub> = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.3	1		
		I <sub>F</sub> = 1 mA	_	715	m∨
		I <sub>F</sub> = 10 mA	_	855	mV
		I <sub>F</sub> = 50 mA	_	1	V
		I <sub>F</sub> = 150 mA	_	1.25	v
I <sub>R</sub>	reverse current	see Fig.5			
		V <sub>R</sub> = 25 V	_	30	nA
		V <sub>R</sub> = 75 V	_	1	μΑ
		V <sub>R</sub> = 25 V; T <sub>j</sub> = 150 °C	_	30	μΑ
		V <sub>R</sub> = 75 V; T <sub>j</sub> = 150 °C	_	50	μΑ
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0; see Fig.6	_	1.5	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F$ = 10 mA to $I_R$ = 10 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 1 mA; see Fig.7	_	4	ns
V <sub>fr</sub>	forward recovery voltage	when switched from $I_F = 10$ mA; $t_r = 20$ ns; see Fig.8	-	1.75	V

## THERMAL CHARACTERISTICS

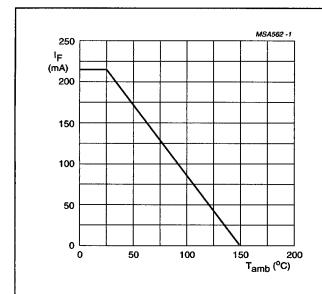
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point		360	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

1. Device mounted on an FR4 printed-circuit board.

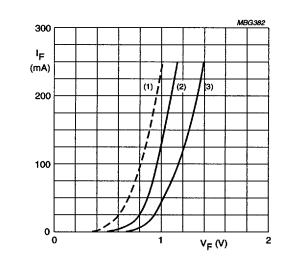
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#### **GRAPHICAL DATA**



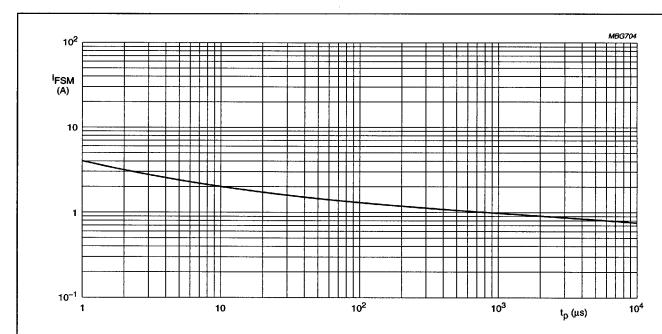
Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1)  $T_j = 150$  °C; typical values.
- (2)  $T_j = 25$  °C; typical values.
- (3) T<sub>j</sub> = 25 °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



Based on square wave currents.

 $T_j = 25~^{\circ}C$  prior to surge.

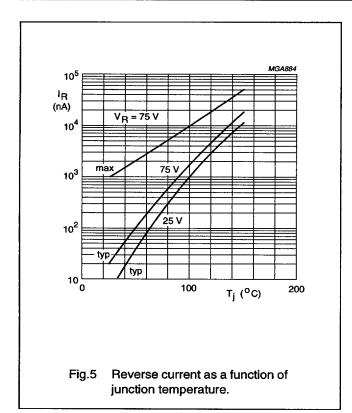
Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

1996 Sep 10

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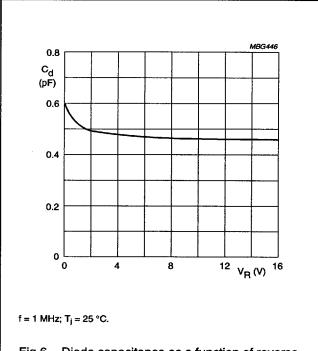
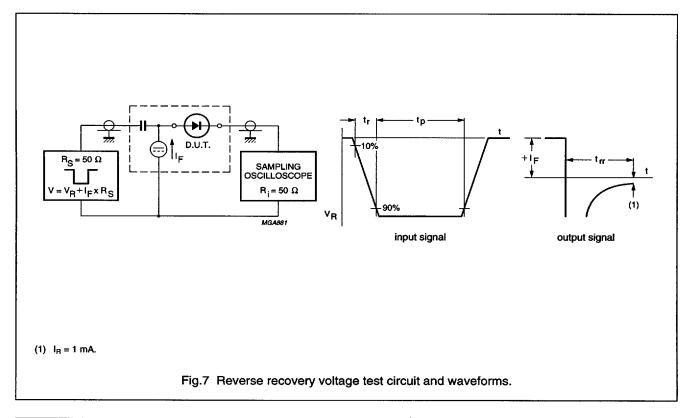
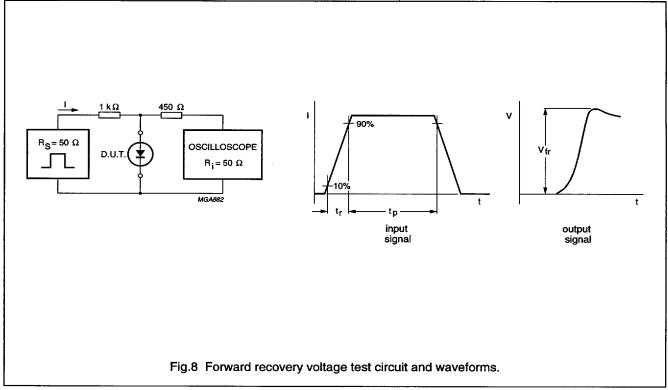


Fig.6 Diode capacitance as a function of reverse voltage; typical values.

BAS28





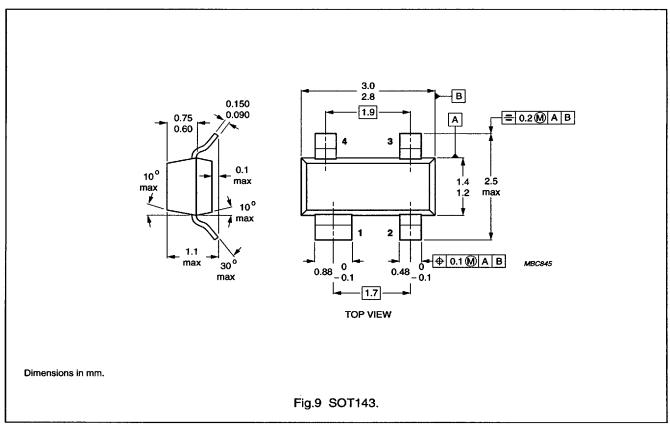
1996 Sep 10

6

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BAS28

#### **PACKAGE OUTLINE**



#### **DEFINITIONS**

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

## **Application information**

Where application information is given, it is advisory and does not form part of the specification.

## LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

1996 Sep 10

7

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